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Disordered Optical Modes for Photon Management

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Wave transport in disordered systems is a vast research topic, ranging from electrons in semiconductors, to light in random dielectrics, to cold atoms in laser speckles. In optics, light transport is conveyed by random electromagnetic modes and the wave can be localized about a point or extended throughout the system, depending on disorder strength, structural correlations and dimensionality of the system. Light localization phenomena are more dominantly present in two-dimensional systems than in three-dimensional ones and their optical modes can be tailored to a greater extent. Here, we show that it is possible to make use of the properties of lower-dimensional disordered structures to obtain photon management in three-dimensional space. More particularly, we argue that two-dimensional disorder and wave interferences can be exploited to improve the performance of light absorbers or emitters. Our findings have direct applications for enhancing the absorption efficiency of third-generation solar cells in a relatively simple and easy-to-implement way and provide unique opportunities for high extraction efficiency light-emitting diodes.

In disordered optical materials, the multiple scattering of light and the interferences between propagating waves lead to the formation of electromagnetic modes with varying spatial extention and lifetime [1–3]. Their superposition gives rise to complex intensity speckle patterns that reflect the underlying transport process. Photon localization [4], in analogy to the Anderson localization of electrons [5], sets in when the scattering is strong or the dimensionality of the system is low. Two-dimensional disordered structures have been the playground over the years for the study of complex optical phenomena, including light localization [6–9] – two being the marginal dimension below which all states, in principle, are localized [10] – and random lasing [11–13]. A greater control over transport is achieved in two-dimensional systems than in three-dimensional ones. Two-dimensional random structures in planar waveguides, in particular, constitute an important critical case that offers interesting possibilities.

Already in the early publications on light localization [14, 15], the absorption of light by a random medium was shown to be considerably enhanced by strong interference effects. Strongly scattering three-dimensional disordered structures appeared as a valuable candidate for designing strong light absorbers for photovoltaics applications [16]. Nowadays, the main challenge taken up by the scientific community in the field of solar energy, however, consists in maximizing the absorption of solar radiation by absorbing layers much thinner than any possible three-dimensional random structure. Thin-film solar cells can benefit a lot from the so-called *photon management*, where a photonic structure is used to "trap" light in the absorbing medium [17]. Current strategies to improve their performance involve the use of plasmonic nanoparticles or gratings [18–20], resonant dielectric particles [21] or two-dimensional deterministic (periodic or quasi-periodic) photonic materials [22–25].

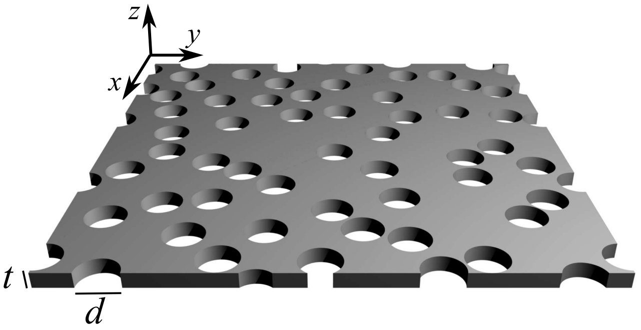

FIG. 1. Sketch view of a thin randomly-nanostructured film with thickness t, circular holes of diameter d and hole filling fraction f. Two-dimensional multiple scattering of light in the film leads to the formation of disordered optical modes to which coupling from free space is possible.

In this paper, we show that two-dimensional disordered patterns of air holes in planar dielectric waveguides provide a conceptually new way to realize highly absorbing thin films. The structure under consideration is realistic and hence, the finite thickness of the film and the light coupling process between the in-plane optical modes and free space are intrinsically part of the physics involved. A delicate interplay between in-plane multiple scattering, out-of-plane losses, and optical absorption determines the optical properties of the system. For thin absorbing films, we find that it is possible to obtain a significant increase of the absorption over a very broad wavelength range, a wide angular range and for both polarizations of incident light – a crucial requisite for photovoltaic technologies. Although the coupling to this optical modes is mediated by interference effects, the highest absorption enhancement is surprisingly not obtained in the frequency range in which they are the strongest, i.e. where the modes are spatially localized. The spectral and angular optical responses can be tuned by adding structural correlations in the disorder, which allows to match the wavelength and bandwidth of the absorption enhancement according to specific needs. The concept has the additional advantage that it is potentially simple to implement on a large scale and is compatible with current thin-film solar cell technologies. In addition to applications for light absorbers, the same concept can be applied to enhance the extraction efficiency of light-emitting diodes for lighting applications, of great interest nowadays [26, 27]. In that case, this allows to create an integrated optical source of diffusive light for which the angular profile can be tuned – a desireable property that is very difficult to obtain with conventional technology.

The system under study is typically a thin dielectric membrane containing a random pattern of circular holes going through the entire film thickness (see Fig. 1). The concepts presented below are valid for any type of two-dimensional random systems of finite thickness and can be applied to any inorganic or organic material. The choice of considering layers with small thicknesses is motivated mainly by the growing demand in thin-film technologies for photovoltaics and the need to enhance the light absorption for a higher photovoltaic efficiency at a lower cost. Let us first go briefly into the main physical concepts that describe light transport in such a structure. Light is essentially confined to the plane of the film by index-guiding. Due to the presence of the holes, which serve as scattering centers, the light waves are multiply-scattered in the plane, giving rise a quasi-two-dimensional type of transport [28]. Because of the finite thickness of the film, however, the optical modes formed by the multiple scattering process are leaky and thus, allow for a coupling process with the third dimension to take place. The high density of states in the film makes such that the single scattering function is very much peaked into the plane, thereby leading to a very efficient light trapping even for planewaves at normal incidence on the slab.

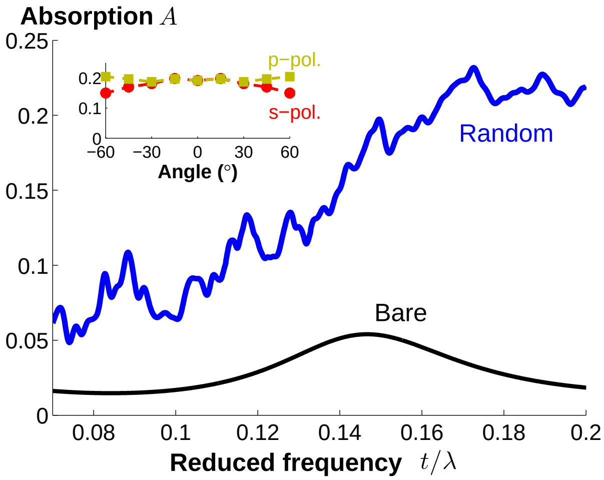

FIG. 2. Absorption spectra of a thin film including a random pattern of holes (blue line) and a bare thin film (black line). The inset shows the angular dependence of the absorption at $t/\lambda = 0.15$ for incident light with s- and p-polarization (red circles and orange squares, respectively). The random pattern of holes leads to a large absorption of the incident light over a wide angular range and for both polarizations.

To demonstrate that this mechanism indeed leads to a very efficient broadband light absorber, we calculate the absorption spectrum for a planewave in air at normal incidence on an absorbing film patterned with circular holes at random positions, as in Fig. 1. The numerical analysis is performed by the three-dimensional Finite-Difference Time-Domain method [29] using periodic boundary conditions on a large area to mimic infinitely large structures. For convenience, all dimensions in this study are given as a function of the film thickness t and can be rescaled according to one's need. Here, the circular holes have a diameter $d = 2.7t$ and filling fraction $f = 30\%$. The material of the film has a permittivity $\epsilon = 12$ and an absorption length $\ell_i = 33t$, which, for the sake of the analysis, was considered constant over the wavelength range of interest. This corresponds approximately to the absorption of a film of amorphous silicon of thickness $t = 75$ nm at a free space wavelength $\lambda \approx 800$ nm [30] and compares well also with the absorption of some organic materials used for thin-film solar cells.

The absorption A of the patterned film is plotted in Fig. 2 together with the absorption of the bare film. We find that the random pattern of holes enhances significantly the absorption of the film over the entire wavelength range under consideration, the integrated absorption being increased by a factor of about 5. This absorption enhancement occurs in spite of the fact that 30% of absorbing material has been removed. The inset of Fig. 2 shows the angular dependence of the absorption at $t/\lambda = 0.15$ for both s- and p-polarizations. One can see that the absorption remains particularly high even at large angles and for both polarizations of the incident light. This is a property of paramount importance for solar panels since it allows to retain a high efficiency also for diffuse illumination.

To gain more insight into the mechanism behind this strong absorption enhancement, it is instructive to observe how the electromagnetic energy density is distributed in the nanostructured film. The repartition of the energy density between a dielectric material and free space allows to determine (at thermal equilibrium) the maximal enhancement of absorption in the material [17, 31, 32]. In Fig. 3, the steady-state electromagnetic energy density distribution in the film is shown for two different frequencies ($t/\lambda = 0.09$ and 0.15), consider-

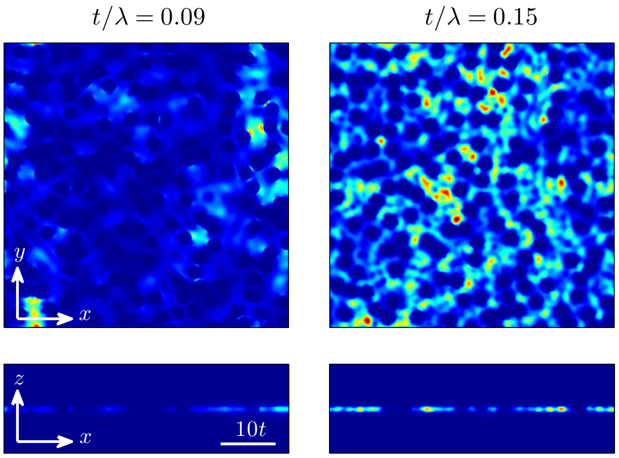

FIG. 3. Top and side views of the electromagnetic energy density inside a non-absorbing sample for an incoming planewave at frequencies $t/\lambda = 0.09$ (left) and $t/\lambda = 0.15$ (right). The normalization on the color scale is made according to the highest value at the specific frequency. The polarization is along the x-direction and the incoming wavevector is at normal incidence to the plane of the slab, along the z-direction. The high energy density in the film implies an efficient light trapping, which explains the high absorption efficiency.

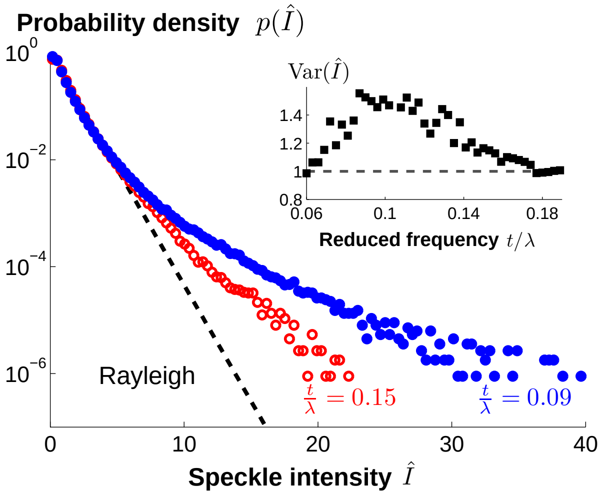

FIG. 4. Speckle intensity distribution $p(\hat{I})$ in the two-dimensional random medium at frequencies $t/\lambda = 0.09$ and 0.15. Strong light scattering and interferences between multiply-scattered waves give rise to slowly-decaying tails in the speckle intensity distribution that deviate from the Rayleigh law (black dashed line). The variance of the distribution (in the inset) shows that interferences between multiply-scattered waves are significant for transport over a broad wavelength range.

ing again an incoming continuous planewave polarized along x at normal incidence on a non-absorbing patterned film with the same structural parameters as in Fig. 2. The remarkably high energy density in the film compared to free space (enhancement factors of about 16 and 40 at $t/\lambda = 0.09$ and 0.15, respectively) indicates a very efficient light trapping. The superposition of the excited in-plane modes is characterized by a spatial pattern dominated by strong fluctuations, inherent to the interferences between multiply-scattered waves. Different levels of spatial confinement can also be observed as a function of frequency. In leaky two-dimensional random media, the typical extention of the modes is expected to rely on the competition between wave localization effects and out-of-plane losses.

The nature of the optical modes in the two-dimensional random medium can be further understood by analyzing the speckle distributions of the field and the intensity induced by the in-plane multiple light scattering. Their analysis allows to investigate how light propagates in the medium and how the coupling process with free space takes place. Since the transport is essentially in the plane of the film, this analysis can be made in purely two-dimensional systems. For the sake of the demonstration, we focus on the lowest-order TE-polarized propagating mode of the slab that is the most relevant for such thicknesses. The refractive index of the dielectric material is set to the effective (frequency-dependent) refractive index of the propagating mode as to account effectively for the finite thickness of the film. A large number of H_z dipole sources with random phases are placed at random positions in the computational domain to excite all possible modes. The spatial field maps recorded after long times then make it possible to retrieve important information on transport.

The speckle intensity distribution, which describes the intensity fluctuations in random media, indicates the nature of the wave transport regime. In the case of an uncorrelated Gaussian disorder, the distribution of speckle intensity is expected to follow the Rayleigh law $p(\hat{I}) \sim \exp(-\hat{I})$ with $\hat{I} = I/\langle I \rangle$ the speckle intensity normalized to its average value. Strong interference effects, such as light localization, typically lead to a strongly fluctuating intensity, characterized by a distribution with a slowly-decaying tail [3]. The speckle intensity in large purely two-dimensional structures, shown in Fig. 4 for $t/\lambda = 0.09$ and 0.15, reveals deviations from the Rayleigh law at large intensities. The intensity fluctuations are larger at the lower of these two frequencies, that is in accordance with the speckle patterns shown in Fig. 3. The variance of the distribution, shown in the inset of Fig. 4, indicates that strong interference effects are significant over a broad wavelength range.

While the speckle intensity distribution gives information on the role of interferences on transport in the medium, a Fourier analysis of the fields makes it possible to infer the nature of the propagating modes in the random media and to extract the average dispersion of the system. The Fourier components of the electric field along the x- and y-directions in the system are shown in Fig. 5A. The complex field pattern in real space is due to the superposition of the different optical modes in the medium. In reciprocal space, it is possible to separate all these modes, each point corresponding to a certain density of (polarized) k-space resonances [33]. For instance, the two lobes observed for both field components correspond to the most probable directions of propagation and their associated propagation constant. Such a study allows to investigate the nature of light coupling between different optical systems [34]. The coupling process between in-plane modes and free space, of particular importance in this study, translates into a phase-matching condition that is met only for in-plane wavevectors $\mathbf{k}_{||}$ lying within the so-called radiation zone, i.e. for $|\mathbf{k}_{||}| < k_0$, with $k_0 = 2\pi/\lambda$ the wavevector in free space.

By making use of the isotropy of the structure, we calculate the radial-averaged density of k-space resonances $M(t/\lambda, k_r) = |\tilde{E}_x(t/\lambda, k_r)|^2 + |\tilde{E}_y(t/\lambda, k_r)|^2$ with $k_r = |\mathbf{k}_{||}|$ at different frequencies, see Fig. 5B, to describe the dispersion of the average propagating mode in the random medium. At lower frequencies, the distribution of resonances exhibits a well-defined peak, corresponding to a propagating mode with a certain effective refractive index. With increasing frequency, the wavelength in the medium becomes comparable to the size of the refractive index fluctuations due to the presence of the holes and, on the occurance of their broad Mie resonances, the peak broadens in reciprocal space [3]. In essence, the k-space resonances lying in the radiation zone, delimited by the light line, are directly related to the in-plane light scattering process. This suggests that the coupling process can be controlled by tuning the structural parameters of the random medium. The k-space resonances span the radiative zone quite uniformly, which explains why the coupling efficiency only depends weakly on the angle of incidence of light from the third dimension. Finally, a large part of the average mode lies out of the radiative zone, implying that light coupled to the film can remain within it for a certain time. In absorbing media, this trapping effect increases the probability for light to be absorbed.

In summary, the distribution of the k-space resonances of purely two-dimensional disordered structures is found to describe well how light propagates in the medium and how in-plane optical modes and free space are coupled to each other. This combination explains the strong absorption enhancement that can be achieved by random patterning. As we will now show, it is possible, in addition, to tune the structural parameters of a random medium to optimize this absorption enhancement and calibrate its spectral response to a desired wavelength band.

We have considered so far a random structure in which the position of the holes was uncorrelated (apart from a non-overlap constraint) and have seen that its optical response does not exhibit sharp spectral and angular features. These optical characteristics, however, can be changed by adding correlations in the disorder. Structural correlations, such as short-range order in amorphous materials, provide an additional degree of freedom to control light transport and interferences in disordered materials [35, 36]. In two-dimensional structures, correlations have been used to create large and isotropic photonic band gaps [37] as well as to gain a better control over random lasing processes [13]. To illustrate the possibilities that structural correlations offer for light coupling purposes, we investigate the optical properties of an *amorphous* structure that possesses a short-range order in the position of the holes but lacks any long-range order (e.g. periodicity).

We calculate the absorption spectrum of the two-dimensional amorphous structures for holes with the same diameter and at the same filling fraction, see Fig. 6A. The effect of short-range correlations on the absorption is striking. While the simple random structure provides a broadband absorption enhancement over the entire range of interest, the amorphous structure exhibits an absorption comparable to that of the bare film at lower frequencies, followed by a large absorption enhancement at frequencies $t/\lambda \approx 0.16$.

This behavior is perfectly explained by the distribution of resonances shown in Fig. 6B for the amorphous case. At frequencies below to $t/\lambda \approx 0.07$, a depletion of the density of k-space resonances in the radiative zone is observed. Due to their very low number, light incident from free space on the film crosses it almost without being scattered. This peculiar phenomenon is specific to our system of finite thickness and illustrates nicely that the coupling process is not a property of the single scatterer but that of the disordered medium as a whole, in both the random and amorphous cases.

This depletion of k-space resonances is in fact accompanied by two other remarkable effects, both of which are inherent to the short-range order in the structure and evidently do not require a long-range periodicity. First, at a frequency $t/\lambda \approx 0.07$, corresponding to the Bragg condition for which the wavelength in the medium $\lambda_e = \lambda/n_e$ equals twice the typical distance a between nearest neighbours, $\lambda_e = 2a$, the dispersion undergoes a strong deformation. The lattice resonance is expected to enhance the in-plane scattering strength in this range [38]. Second, above this frequency, a branch with a negative slope is observed, strongly reminding the dispersion relations of periodically-nanostructured photonic crystals [39]. On the occurance of this new dispersion branch for $k_r = 0$, the number of leaky resonances is strongly increased, thereby explaining the stronger absorption in this range. Furthermore, while the coupling to the random system is expected to be efficient at all angles, the folded branch

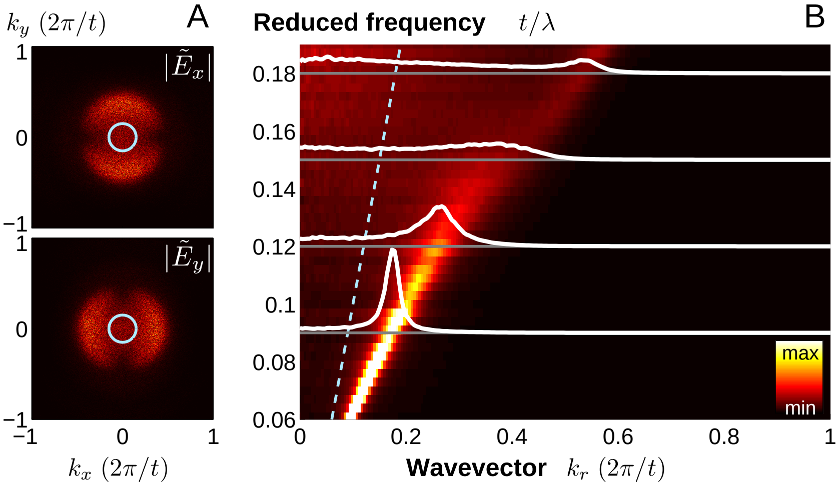

FIG. 5. (A) Distribution of the Fourier transform of the electric field components in the plane of the film, $|\tilde{E}_x|$ and $|\tilde{E}_y|$, at the frequency $t/\lambda = 0.15$. Two-dimensional multiple scattering and wave interferences lead to the formation of complex optical modes, the superposition of which give complex speckle patterns. Light incident on such a random medium from the third dimension can couple to the structure through the k-space resonances lying in the radiative zone (central disk delimited by a light blue solid circle). (B) Radial-averaged density of k-space resonances $M(t/\lambda, k_r)$ in the two-dimensional random structure and the white lines are cross-cuts of the resonance distribution at frequencies $t/\lambda = 0.09$, 0.12, 0.15 and 0.18. The light line is shown as a light blue dashed line. The leaky resonances in the radiation zone, above the light line, make the coupling between free space and in-plane modes possible.

in the amorphous structure makes such that coupling at an angle may be more efficient in some frequency range. Disorder correlations therefore allow for a tuning of both the spectral and the angular light coupling of two-dimensional disordered media. For applications in lighting, one could take advantage of the negatively-sloped branch in amorphous structures to design light-emitting diodes with some iridescent *diffuse* light. All in all, structures with correlated disorder are promising candidates for future integrated optical devices, as imposing only a weak constraint on the position of the scattering elements, such as a minimum distance, is enough to induce radically different optical characteristics.

Finally, a critical parameter for the description of light absorption or extraction in thin films is the average lifetime of the modes τ. In particular, it is known that the absorption efficiency of nanostructured thin-film solar cells relies on a delicate interplay between the leakage rate and the absorption rate of the material [17]. Typically, a good compromise in terms of efficiency and bandwidth is found when both rates are comparable. On the other hand, in light-emitting diodes, light should be extracted as fast as possible to avoid any possible re-absorption by the device [26, 27]. In this case, the average lifetime of the modes should preferably be much smaller than the absorption time of the material. As the average lifetime of the modes in disordered systems depend intrinsically on the multiple scattering process, we expect it to be tunable by scattering strength and disorder correlations in thin two-dimensional disordered media.

To investigate this possibility, we calculate the average lifetime of the modes in the real (three-dimensional) random and amorphous structures by performing a temporal Fourier analysis of the decay of the field in the structure after excitation by many dipoles. In Fig. 7, the lifetime is compared with the total number of leaky resonances in the system per unit frequency, evaluated as $N_l(a/\lambda) = \int\int_{|\mathbf{k}_{||}|<k_0} M(a/\lambda, \mathbf{k}_{||}) d\mathbf{k}_{||}$ from the resonance distribution of the corresponding two-dimensional structures. At higher frequencies, the lifetime of the modes in the random and amorphous systems are very comparable, due to the fact that the number of k-space resonances lying in the radiative zone is almost the same in both systems. In contrast, at lower frequencies, the lifetime of the modes in the amorphous system becomes extremely long, as a result from the depletion by about an order of magnitude of the number of such resonances at frequencies close to $t/\lambda \approx 0.07$. This phenomenon agrees with the previous analysis showing that the amorphous material in this frequency range can be transparent to light incident from the third dimension. In essence, this shows that the average lifetime of the modes in the system can be controlled by its structural parameters, thereby opening the way for the design of innovative disordered photonic structures with specific optical properties.

In conclusion, controlling the light coupling process between free space and thin or ultrathin films is a topic of

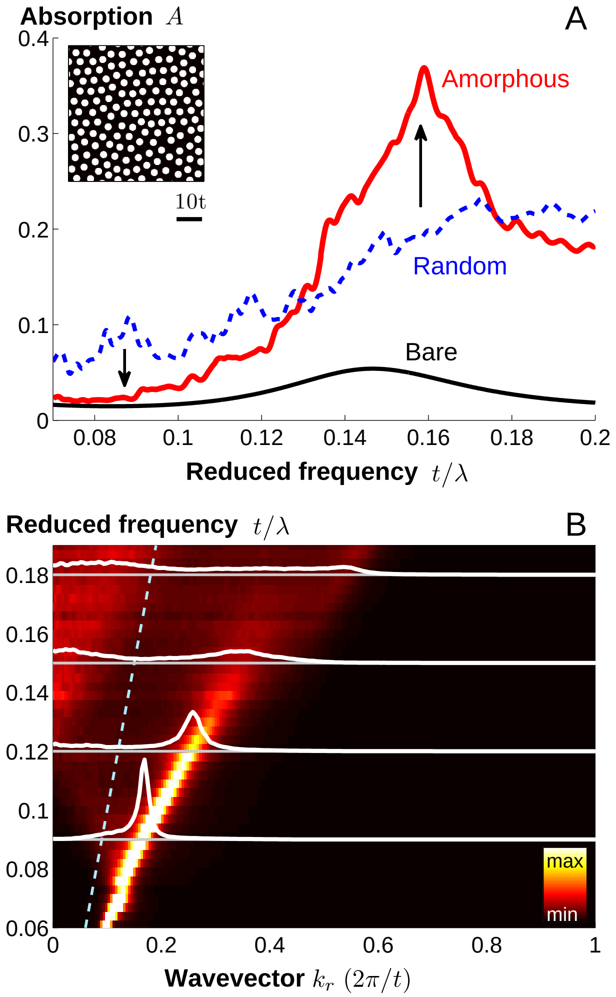

FIG. 6. (A) Absorption spectrum of a two-dimensional amorphous structure (red solid line), compared to the absorption spectrum of bare film (black line) and of the random structure (blue dashed line). The modelled amorphous structure is shown in the inset. (B) Radial-averaged density of k-space resonances $M(t/\lambda, k_r)$, as in Fig. 4, in the two-dimensional amorphous structure. The amorphous structure, due to structural correlations, leads to a larger increase of the absorption on a smaller spectral range compared to the simple random case. The reduced and enhanced absorption are explained by the depletion and increase of the density of resonances for a planewave at normal incidence on the film at lower and higher frequencies, respectively.

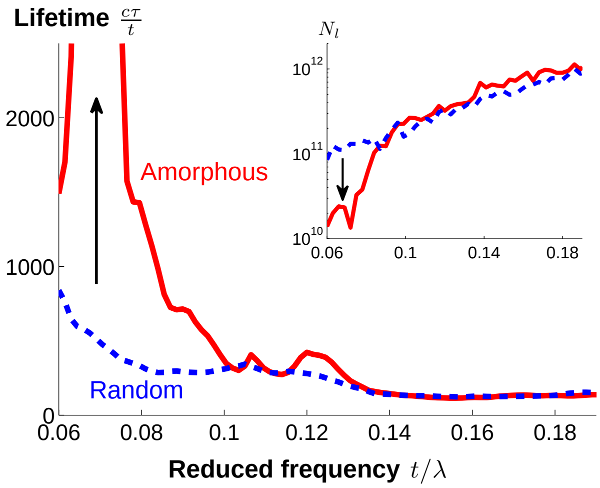

FIG. 7. Average lifetime of the modes in the two-dimensional random (blue dashed line) and amorphous (red solid line) structures. The inset shows the number of leaky resonances per unit frequency in the random and amorphous structures. The depletion in the number of leaky resonances in the amorphous structures at frequencies $t/\lambda \approx 0.07$ leads to a remarkable increase of the average lifetime of the modes.

great interest for many applications, in particular in the field of energy efficiency. In this paper, we have proposed an original way to take up this challenge, namely that of using the optical modes formed by the multiple scattering of light in two-dimensional disordered media of finite thickness. We have shown in particular that the strength of the in-plane scattering and the structural correlations in the disorder offer the possibility to tune the spectral and angular optical properties of the light coupling process, as well as the average lifetime of the modes. Such disordered patterns are likely to be easier to implement on an industrial scale compared to their periodic counterpart, as no long-range order is required and the optical properties of the material are far more robust to structural imperfections. For these reasons, we believe that two-dimensional disordered materials could form a new generation of high-efficiency (inorganic or organic) thin-film photovoltaic devices and light sources.

By bringing the physics of random media into the field of energy efficiency, this study also opens the route towards the use of complex optical phenomena of interest so far for fundamental science mainly, such as light localization, for future technologies. For instance, light emitters (e.g. quantum dots) embedded in such two-dimensional disordered media of finite thickness would see their rate of spontaneous emission dramatically increase due to a very strong light-matter interaction, as observed recently in disordered one-dimensional photonic crystal waveguides [40]. By a clever disorder engineering, one may possibly boost up the light emission efficiency in thin films in specific frequency ranges.

Finally, let us emphasize the fact that the concepts presented in this article rely on the properties of waves in general and thus, are not restricted to electromagnetic waves in the optical range. Thin two-dimensional disordered structures could be designed to operate for microwaves or sound waves, and be used for shielding applications. Two-dimensional random media of finite thickness are rich of new physical concepts for wave management in three-dimensional space. This article paves the way for more research in this direction as well as for the development of concrete applications.

Methods

The random structures, on one hand, were generated by Random Sequential Addition [41] of hard circular cylinders at a filling fraction of 30% on a square area with periodic boundary conditions. The amorphous structures, on the other hand, were generated by the Lubachevsky-Stillinger algorithm on the same area [42]. This algorithm was used to impose short-range disorder correlations in the position of the cylinders. To avoid the formation of large ordered clusters, as in polycrystalline structures, a polydispersity of 1.1 in the size of the cylinders was used. The growth of the cylinders was stopped at a filling fraction of 69% and their diameter was set to a constant diameter such that the final filling fraction would be 30%.

For the refractive index of the dielectric medium in the two-dimensional calculations, we used the effective index of refraction of the lowest-order TE propagating mode, calculated by an online mode solver for multilayered media [43] at different wavelengths. A polynomial fit was used to model the refractive index of the dielectric film over the entire range of interest: $n_s = 3.6446 - 0.1074\left(\frac{\lambda}{t}\right) - 2.213\,10^{-3}\left(\frac{\lambda}{t}\right)^2 + 1.744\,10^{-4}\left(\frac{\lambda}{t}\right)^3$. For the effective refractive index of the two-dimensional randomly patterned array, the two-dimensional Maxwell-Garnett mixing rule can be used: $n_e = n_s\sqrt{1 + \frac{2f\alpha}{1-f\alpha}}$, with $\alpha = \frac{n_c^2 - n_s^2}{n_c^2 + n_s^2}$ with $n_c = 1$ the refractive index of the cylinders and n_s the effective refractive index of the lowest-order TE propagating mode defined above.

Simulations were performed with the Finite-Difference Time-Domain method [29] using a freely available software package [44]. The mesh resolution was set to have at least 10 grid points per wavelength in the higher refractive index material. Periodic boundary conditions in the lateral directions (x and y) were used in all simulations. The lateral size of the computational domain was $L = 200t$ in the two-dimensional calculations and $L = 50t$ in the three-dimensional calculations. The absorption A was calculated by recording the reflected and transmitted fluxes, R and T, respectively, for long times under excitation by planewave pulses at different frequencies, and calculating $A = 1 - T - R$. For the studies on the two-dimensional speckle field and intensity distribution of the random and amorphous structures, a total of 2000 dipoles, uniformly distributed throughout the entire computational domain and with random phases, was used. For the lifetime calculations in the three-dimensional structures, 640 E_x, E_y and E_z dipoles were placed at random positions in the film and the decay of the electric field was recorded at 20 different points uniformly distributed in the film.

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[1] J. Wang and A. Z. Genack, Nature **471**, 345 (Mar. 2011), ISSN 0028-0836

[2] E. Akkermans and G. Montambaux, *Mesoscopic Physics of Electrons and Photons*, 1st ed. (Cambridge University Press, 2007) ISBN 0521855128

[3] P. Sheng, *Introduction to Wave Scattering, Localization and Mesoscopic Phenomena*, 2nd ed. (Springer, 2010) ISBN 3642067123

[4] A. Lagendijk, B. van Tiggelen, and D. S. Wiersma, Physics Today **62**, 24 (2009)

[5] P. W. Anderson, Physical Review **109**, 1492 (Mar. 1958)

[6] P. Sebbah, D. Sornette, and C. Vanneste, Physical Review B **48**, 12506 (Nov. 1993)

[7] M. M. Sigalas, C. M. Soukoulis, C.-T. Chan, and D. Turner, Physical Review B **53**, 8340 (1996)

[8] T. Schwartz, G. Bartal, S. Fishman, and M. Segev, Nature **446**, 52 (Mar. 2007), ISSN 0028-0836

[9] F. Riboli, P. Barthelemy, S. Vignolini, F. Intonti, A. D. Rossi, S. Combrie, and D. S. Wiersma, Optics Letters **36**, 127 (Jan. 2011)

[10] D. Vollhardt and P. Wölfle, Physical Review B **22**, 4666 (Nov. 1980)

[11] P. Sebbah and C. Vanneste, Physical Review B **66**, 144202 (Oct. 2002)

[12] J. Andreasen, A. A. Asatryan, L. C. Botten, M. A. Byrne, H. Cao, L. Ge, L. Labonté, P. Sebbah, A. D. Stone, H. E. Türeci, and C. Vanneste, Advances in Optics and Photonics **3**, 88 (2011)

[13] H. Noh, J. Yang, S. F. Liew, M. J. Rooks, G. S. Solomon, and H. Cao, Physical Review Letters **106**, 183901 (May 2011)

[14] S. John, Physical Review Letters **53**, 2169 (Nov. 1984)

[15] P. Anderson, Philosophical Magazine Part B **52**, 505 (Sep. 1985), ISSN 1364-2812

[16] O. L. Muskens, J. G. Rivas, R. E. Algra, E. P. A. M. Bakkers, and A. Lagendijk, Nano Letters **8**, 2638 (2008)

[17] Z. Yu, A. Raman, and S. Fan, Proceedings of the National Academy of Sciences **107**, 17491–17496 (2010)

[18] H. A. Atwater and A. Polman, Nature Materials **9**, 205 (Mar. 2010), ISSN 1476-1122

[19] S. Pillai and M. A. Green, Solar Energy Materials and Solar Cells **94**, 1481 (2010)

[20] V. E. Ferry, M. A. Verschuuren, M. C. van Lare, R. E. I. Schropp, H. A. Atwater, and A. Polman, Nano Letters **11**, 4239 (2011)

[21] Y. Yao, J. Yao, V. K. Narasimhan, Z. Ruan, C. Xie, S. Fan, and Y. Cui, Nature Communications **3**, 664 (2012)

[22] S. Zanotto, M. Liscidini, and L. C. Andreani,

Optics Express **18**, 4260 (2010)

[23] X. Meng, G. Gomard, O. El Daif, E. Drouard, R. Orobtchouk, A. Kaminski, A. Fave, M. Lemiti, A. Abramov, P. Roca i Cabarrocas, and C. Seassal, Solar Energy Materials and Solar Cells **95**, S32 (2011)

[24] C. Battaglia, J. Escarré, K. Söderström, M. Charrière, M. Despeisse, F.-J. Haug, and C. Ballif, Nature Photonics **5**, 535 (2011)

[25] S. B. Mallick, M. Agrawal, A. Wangperawong, E. S. Barnard, K. K. Singh, R. J. Visser, M. L. Brongersma, and P. Peumans, Applied Physics Letters **100**, 053113 (2012)

[26] A. Zhmakin, Physics Reports **498**, 189 (Feb. 2011), ISSN 0370-1573

[27] C. Wiesmann, K. Bergenek, N. Linder, and U. Schwarz, Laser & Photonics Review **3**, 262 (Apr. 2009), ISSN 18638880

[28] S. Gottardo, S. Cavalieri, O. Yaroshchuk, and D. S. Wiersma, Physical Review Letters **93**, 263901 (2004)

[29] A. Taflove and S. C. Hagness, *Computational Electrodynamics: The Finite-Difference Time-Domain Method, Third Edition*, 3rd ed. (Artech House Publishers, 2005) ISBN 1580538320

[30] E. D. Palik, *Handbook of Optical Constants of Solids* (Academic Press, 1997)

[31] E. Yablonovitch, Journal of the Optical Society of America **72**, 899 (1982)

[32] D. M. Callahan, J. N. Munday, and H. A. Atwater, Nano Letters **12**, 214 (2012)

[33] R. J. P. Engelen, Y. Sugimoto, H. Gersen, N. Ikeda, K. Asakawa, and L. Kuipers, Nature Physics **3**, 401 (2007)

[34] M. Burresi, D. van Oosten, B. S. Song, S. Noda, and L. Kuipers, Optics Letters **36**, 1827 (2011)

[35] S. Fraden and G. Maret, Physical Review Letters **65**, 512 (Jul. 1990)

[36] L. F. Rojas-Ochoa, J. M. Mendez-Alcaraz, J. J. Saenz, P. Schurtenberger, and F. Scheffold, Physical Review Letters **93**, 073903 (2004)

[37] M. Florescu, S. Torquato, and P. J. Steinhardt, Proceedings of the National Academy of Sciences **106**, 20658 (Dec. 2009)

[38] J. Yang, C. Schreck, H. Noh, S. Liew, M. I. Guy, C. S. O'Hern, and H. Cao, Physical Review A **82**, 053838 (Nov. 2010)

[39] J. D. Joannopoulos, S. G. Johnson, J. N. Winn, and R. D. Meade, *Photonic Crystals: Molding the Flow of Light*, 2nd ed. (Princeton University Press, 2008) ISBN 0691124566

[40] L. Sapienza, H. Thyrrestrup, S. Stobbe, P. D. Garcia, S. Smolka, and P. Lodahl, Science **327**, 1352 (2010)

[41] S. Torquato, *Random Heterogeneous Materials*, corrected ed. (Springer, 2001) ISBN 0387951679

[42] M. Skoge, A. Donev, F. H. Stillinger, and S. Torquato, Physical Review E **74**, 041127 (2006)

[43] M. Hammer, `http://wwwhome.math.utwente.nl/~hammer/oms.html`

[44] A. F. Oskooi, D. Roundy, M. Ibanescu, P. Bermel, J. D. Joannopoulos, and S. G. Johnson, Computer Physics Communications **181**, 687 (2010)